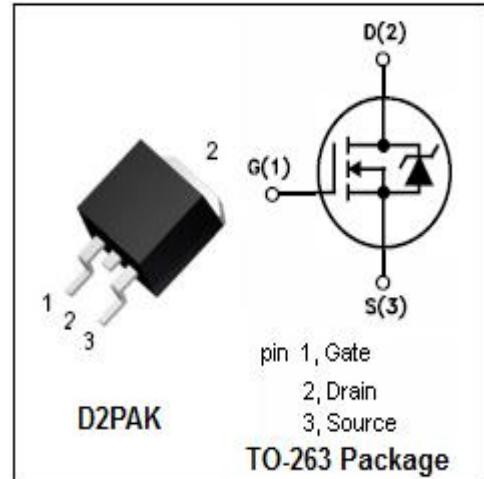


## Isc N-Channel MOSFET Transistor

**IPB035N08N3G**

### • FEATURES

- With TO-263( D<sup>2</sup> PAK ) packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### • APPLICATIONS

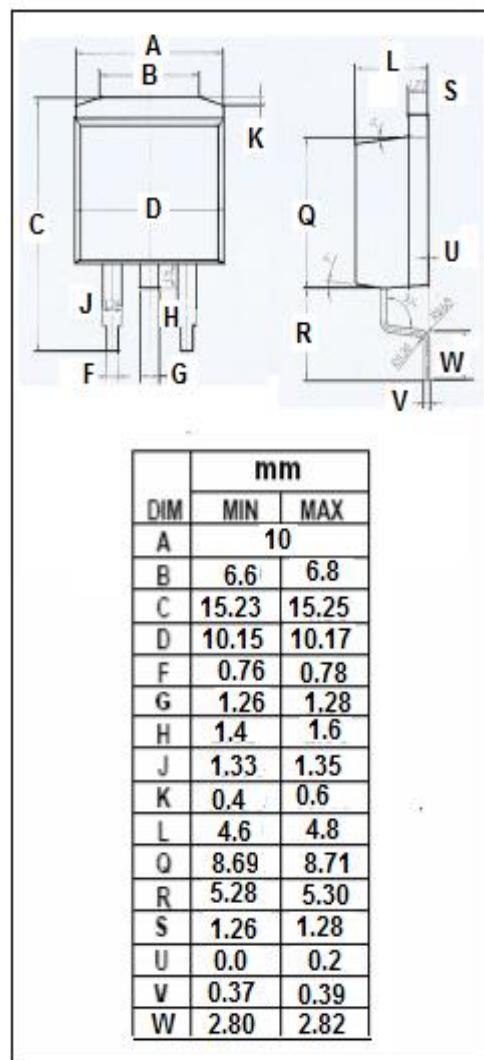
- Power supply
- Switching applications

### • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	80	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	100	A
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	214	W
T <sub>j</sub>	Max. Operating Junction Temperature	-55~175	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Channel-to-case thermal resistance	0.7	°C/W



**Isc N-Channel MOSFET Transistor****IPB035N08N3G****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_\text{D}= 1\text{mA}$	80			V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{I}_\text{D}= 155 \mu\text{A}$	2	2.8	3.5	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_\text{D}=100\text{A}$		3.1	3.75	$\text{m}\Omega$
$\text{I}_{\text{GSS}}$	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			$\pm 100$	nA
$\text{I}_{\text{DSS}}$	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 80\text{V}; \text{V}_{\text{GS}}= 0\text{V}$		0.1	1	$\mu\text{A}$
$\text{V}_{\text{SD}}$	Diode forward voltage	$\text{I}_\text{S}= 100\text{A}, \text{V}_{\text{GS}} = 0\text{V}$		1	1.2	V

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